## **Electronic Supplementary Information**

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**Figure 2S.** HRTEM of GNS N<sub>2</sub>H<sub>4</sub> (a), GNS KBH<sub>4</sub> (b), GNS 500 (c) and GNS 800 (d). Bar is 8nm for (a) and (b), and 6nm for (c) and (d).





**Tem perature /C Figure 4S.** TG curves of GO and GNS. Heating rate 5 °C min<sup>-1</sup> under air (unless otherwise stated).

<b>Table 15.</b> Elemental analysis of the graphenes.									
Sample	С	Н	Ν	S	0	C/O	C/O		
	(% ms)	(EA)	(XPS)						
GO	45.67	2.44	0.04	1.68	42.38	1.08	3.37		
GNS N <sub>2</sub> H <sub>4</sub>	71.08	1.16	5.82	0.01	13.34	5.33	5.63		
GNS KBH <sub>4</sub>	66.47	1.41	0.12	0.00	21.62	3.07	6.95		
GNS 300	69.51	0.66	0.22	0.30	22.63	3.07	5.92		
GNS 500	76.53	0.67	0.30	0.00	15.48	4.94	6.46		
GNS 800	81.93	0.80	0.12	0.00	8.27	9.91	6.88		

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Commlo	Rate	Cycle number					
Sample		2	10	20	50	100	
GNS N <sub>2</sub> H <sub>4</sub>	1C	734	536	491	397	374	
	C/5	1292	907	832	655	688	
CNS LIDII	1C	410	286	214	208	202	
GNS KBH <sub>4</sub>	C/5	552	343	284	260	251	
CNS 200	1C	759	612	520	368	300	
GN9 200	C/5	941	762	673	506	488	
CINE 500	1C	681	537	486	368	277	
GIV9 200	C/5	750	644	524	381	354	
CINC 900	1C	308	267	234	218	229	
GINS 800	C/5	411	341	308	270	279	

**Table 2S.** Specific capacity (mAh g<sup>-1</sup>) delivered by the half-cells after different number of cycles.